

# **Device Modeling Report**

**COMPONENTS:**

**DIODE/ SCHOOTTKY RECTIFIER / STANDARD**

**PART NUMBER: S15SCA4M**

**MANUFACTURER: SHINDENGEN**

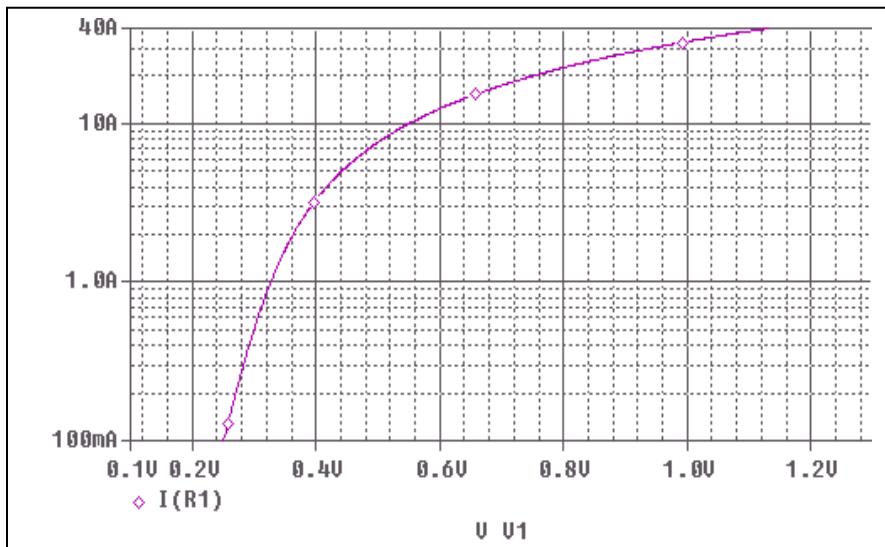


**Bee Technologies Inc.**

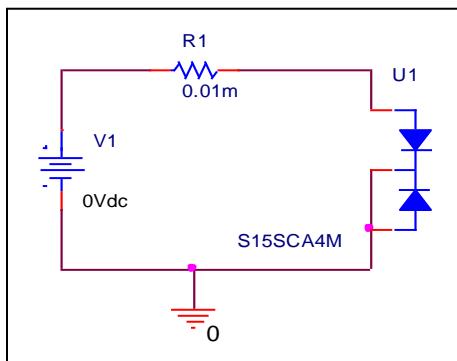
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

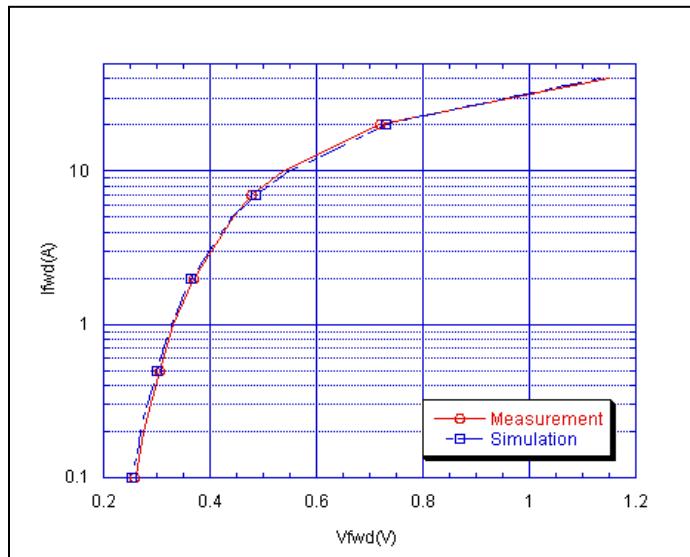


Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

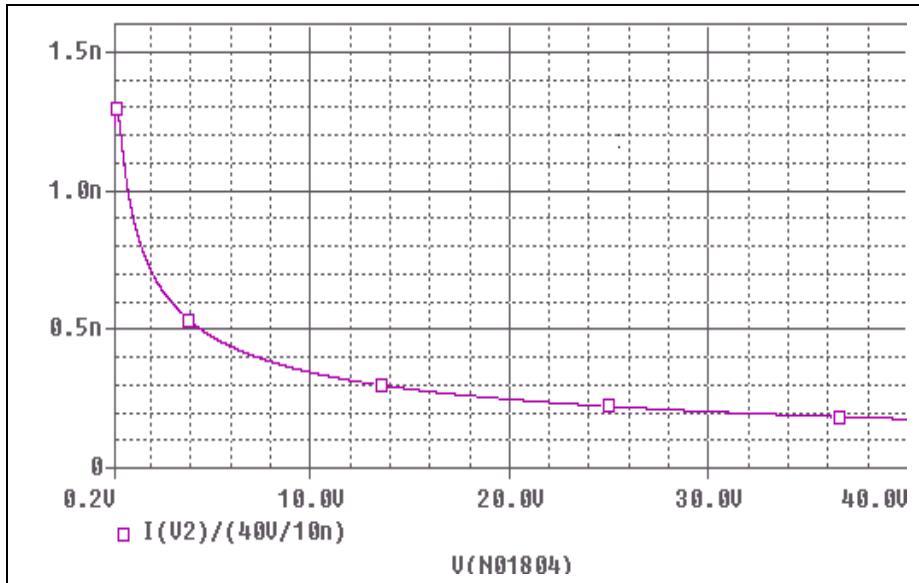


Simulation Result

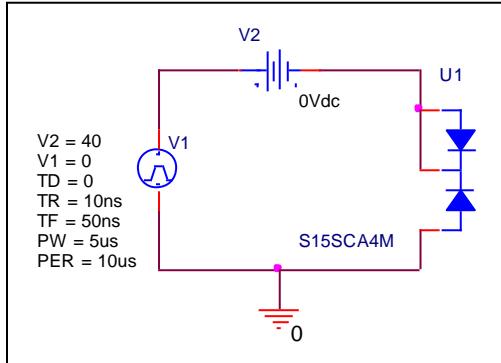
$I_{fwd}$ (A)	$V_{fwd}$ (V) Measurement	$V_{fwd}$ (V) Simulation	%Error
0.1	0.258	0.253	-1.94
0.2	0.274	0.270	-1.35
0.5	0.305	0.300	-1.64
1	0.330	0.327	-1.00
2	0.370	0.363	-1.86
5	0.445	0.441	-0.88
10	0.540	0.550	1.85
20	0.720	0.730	1.39
40	1.150	1.132	-1.57

## Junction Capacitance Characteristic

Circuit Simulation Result

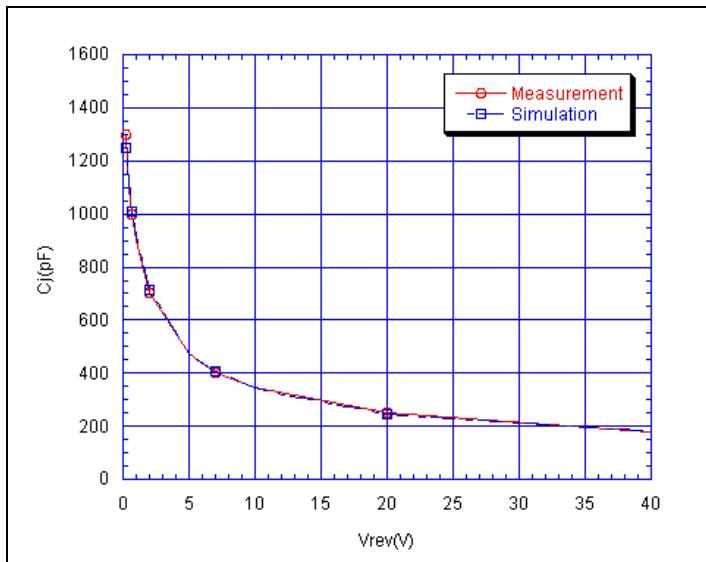


Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result



### Simulation Result

$V_{rev}$ (V)	$C_j$ (pF) Measurement	$C_j$ (pF) Simulation	%Error
1	896.00	920.00	2.68
2	700.00	713.10	1.87
5	475.00	476.60	0.34
10	348.00	345.40	-0.75
20	250.00	247.30	-1.08
40	175.00	177.00	1.14